Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

Fairchild Semiconductor FDZ391P

For any questions, you can email us directly: sales@integrated-circuit.com





November 2008

FDZ391P

P-Channel 1.5 V PowerTrench[®] Thin WL-CSP MOSFET -20 V, -3 A, 85 m Ω

Features

- Max $r_{DS(on)}$ = 85 m Ω at V_{GS} = -4.5 V, I_D = -1 A
- Max $r_{DS(on)} = 123 \text{ m}\Omega$ at $V_{GS} = -2.5 \text{ V}$, $I_D = -1 \text{ A}$
- Max $r_{DS(on)}$ = 200 m Ω at V_{GS} = -1.5 V, I_D = -1 A
- Occupies only 1.5 mm² of PCB area
- Ultra-thin package: less than 0.4 mm height when mounted to PCB
- RoHS Compliant

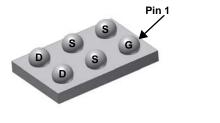


General Description

Designed on Fairchild's advanced 1.5 V PowerTrench process with state of the art "low pitch" **Thin** WLCSP packaging process, the FDZ391P minimizes both PCB space and $r_{\text{DS}(\text{on})}.$ This advanced WLCSP MOSFET embodies a breakthrough in packaging technology which enables the device to combine excellent thermal transfer characteristics, ultra-low profile packaging, low gate charge, and low $r_{\text{DS}(\text{on})}.$

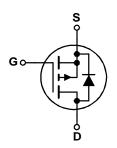
Applications

- Battery management
- Load switch
- Battery protection





TOP



воттом

MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Parameter		Ratings	Units	
V_{DS}	Drain to Source Voltage			-20	V
V_{GS}	Gate to Source Voltage			±8	V
	Drain Current -Continuous	T _A = 25 °C	(Note 1a)	-3	۸
I _D	-Pulsed			-15	A
Б	Power Dissipation	T _A = 25 °C	(Note 1a)	1.9	w
P_{D}	Power Dissipation	T _A = 25 °C	(Note 1b)	0.9	VV
T _J , T _{STG}	Operating and Storage Junction Temp	perature Range		-55 to +150	°C

Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	65	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	133	C/VV

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
6	FDZ391P	WL-CSP Thin	7 "	8 mm	5000 units



Distributor of Fairchild Semiconductor: Excellent Integrated System Limited

Datasheet of FDZ391P - MOSFET P-CH 20V 3A 6-WLCSP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

Electrical Characteristics T_J = 25 °C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	$I_D = -250 \mu A, V_{GS} = 0 V$	-20			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	I_D = -250 μ A, referenced to 25 °C		-12		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -16 \text{ V}, \ V_{GS} = 0 \text{ V}$			-1	μΑ
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 8 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA

On Characteristics

V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = -250 \mu A$	-0.4	-0.6	-1.5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	I_D = -250 μ A, referenced to 25 °C		2		mV/°C
		$V_{GS} = -4.5 \text{ V}, I_D = -1 \text{ A}$		74	85	
	Drain to Source On Resistance	$V_{GS} = -2.5 \text{ V}, I_D = -1 \text{ A}$		90 123 mΩ		
r _{DS(on)}	Diam to Source On Resistance	$V_{GS} = -1.5 \text{ V}, I_D = -1 \text{ A}$		140	200	11152
		$V_{GS} = -4.5 \text{ V}, I_D = -1 \text{ A T}_J = 125 \text{ °C}$		100	123	
I _{D(on)}	On to State Drain Current	$V_{GS} = -4.5 \text{ V}, \ V_{DS} = -5 \text{ V}$	-10			Α
9 _{FS}	Forward Transconductance	$V_{DS} = -5 \text{ V}, I_{D} = -1 \text{ A}$		7		S

Dynamic Characteristics

C _{iss}	Input Capacitance	V 40 V V 0 V	800	1065	pF
Coss	Output Capacitance	V _{DS} = -10 V, V _{GS} = 0 V, -f = 1 MHz	155	205	pF
C _{rss}	Reverse Transfer Capacitance	1 - 1 101112	90	135	pF
R_q	Gate Resistance	f = 1 MHz	9		Ω

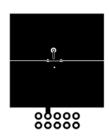
Switching Characteristics

t _{d(on)}	Turn-On Delay Time		11	20	ns
t _r	Rise Time	$V_{DD} = -10 \text{ V}, I_{D} = -1 \text{ A}$ $V_{GS} = -4.5 \text{ V}, R_{GEN} = 6 \Omega$	10	20	ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = -4.5 \text{ V}, R_{GEN} = 6.12$	50	80	ns
t _f	Fall Time		30	48	ns
Q_g	Total Gate Charge	V _{GS} = -4.5 V	9	13	nC
Q _{gs}	Gate to Source Gate Charge	V _{DD} = -10 V	1		nC
Q _{gd}	Gate to Drain "Miller" Charge	I _D = -1 A	2		nC

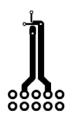
Drain-Source Diode Characteristics

I _S	Maximum continuous Drain-Source Diode	Forward Current		-1.1	Α
V_{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_{S} = -1.1 \text{ A}$ (Note 2)	-0.7	-1.2	٧
t _{rr}	Reverse Recovery Time	I _F = -1 A, di/dt = 100 A/μs	21		ns
Q _{rr}	Reverse Recovery Charge	TF = -1 A, αι/αι = 100 A/μS	5		nC

^{1.} R_{0,M} is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R_{0,C} is guaranteed by design while R_{0CA} is determined by the user's board design.



a. 65 °C/W when mounted on a 1 in² pad of 2 oz copper.



b. 133 °C/W when mounted on a minimum pad of 2 oz copper.

2. Pulse Test: Pulse Width < 300μ s, Duty cycle < 2.0%.

www.fairchildsemi.com 2 FDZ391P Rev.B1





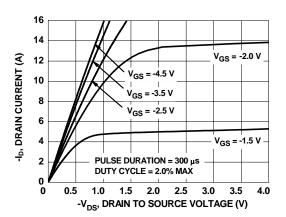


Figure 1. On Region Characteristics

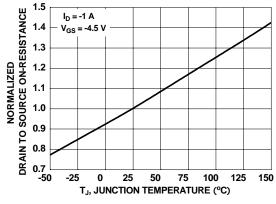


Figure 3. Normalized On Resistance vs Junction Temperature

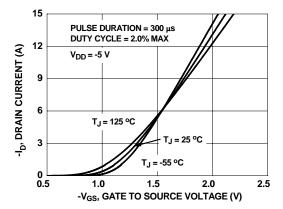


Figure 5. Transfer Characteristics

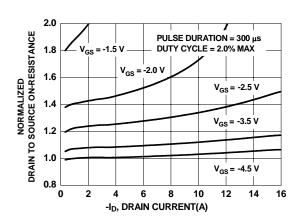


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

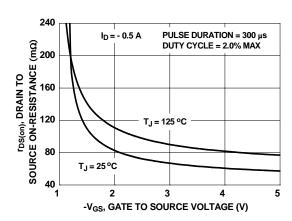


Figure 4. On-Resistance vs Gate to Source Voltage

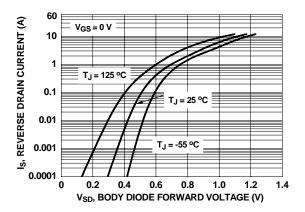


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

FDZ391P Rev.B1 3 www.fairchildsemi.com

Typical Characteristics T_J = 25 °C unless otherwise noted

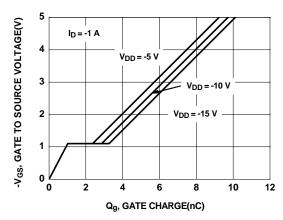


Figure 7. Gate Charge Characteristics

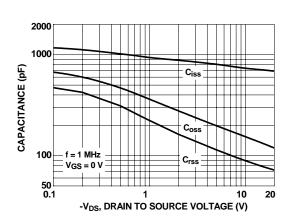


Figure 8. Capacitance vs Drain to Source Voltage

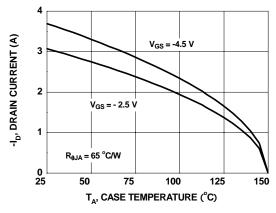


Figure 9. Maximum Continuous Drain Current vs Ambient Temperature

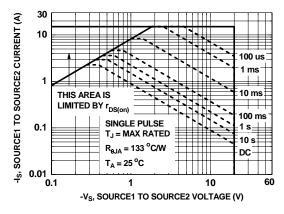


Figure 10. Forward Bias Safe Operating Area

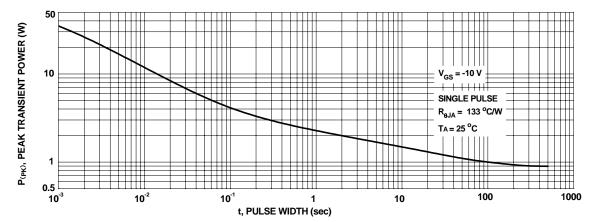


Figure 11. Single Pulse Maximum Power Dissipation

FDZ391P Rev.B1 4 www.fairchildsemi.com

Typical Characteristics T_J = 25 °C unless otherwise noted

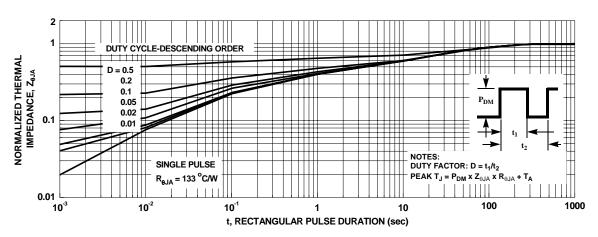
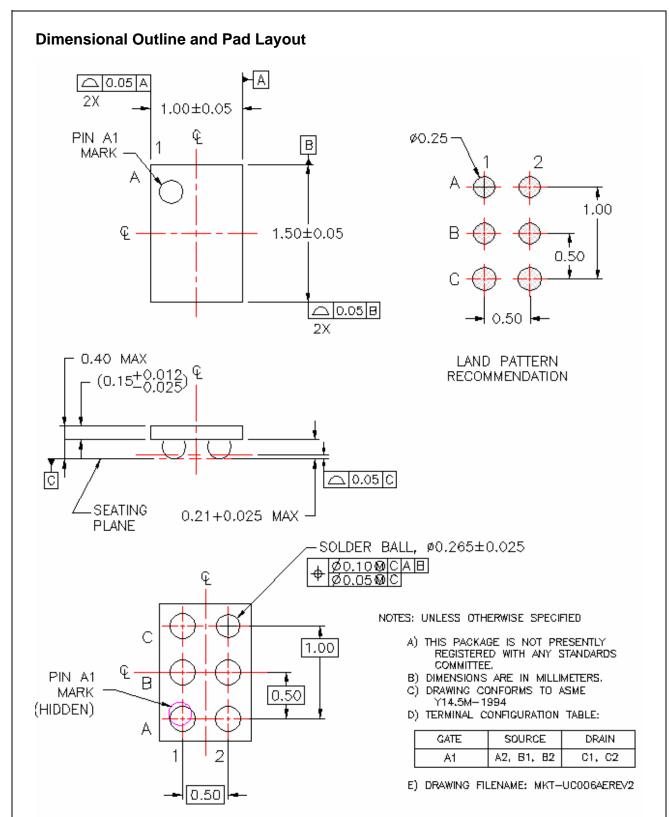


Figure 12. Transient Thermal Response Curve

FDZ391P Rev.B1 5 www.fairchildsemi.com







Distributor of Fairchild Semiconductor: Excellent Integrated System Limited Datasheet of FDZ391P - MOSFET P-CH 20V 3A 6-WLCSP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

Build it NowTM
CorePLUSTM
CorePOWERTM
CROSSVOLTTM
CTLTM

CTL™
Current Transfer Logic™
EcoSPARK®
EfficentMax™
EZSWITCH™ *

Fairchild®

Fairchild Semiconductor® FACT Quiet Series™ FACT®

FACT®
FAST®
FastvCore™
FlashWriter® *
FPS™
F-PFS™

FRFET®

Global Power ResourceSM Green FPSTM Green FPSTM e-SeriesTM GTOTM

IntelliMAXTM
ISOPLANARTM
MegaBuckTM
MICROCOUPLERTM
MicroFETTM
MicroPakTM
MillsoPairsoTM

MicroPak[™]
MillerDrive[™]
MotionMax[™]
Motion-SPM[™]
OPTOLOGIC[®]
OPTOPLANAR[®]

PDP SPM™ Power-SPM™ PowerTrench® PowerXS™ Programmable Active Droop™

QSTM
Quiet SeriesTM
RapidConfigureTM

TM
Saving our world, 1mW /W /kW at a time™
SmartMax™
SMART START™
SPM®
STEALTH™
SuperFET™
SuperSOT™-3

SuperSOTTM-6
SuperSOTTM-8
SupreMOSTM
SyncFETTM

SYSTEM ®

The Power Franchise®

the properties of the propert

SerDes
UHC®
Ultra FRFET™
UniFET™
VCX™
VisualMax™
XS™

* EZSWITCH™ and FlashWriter® are trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY

EIFE SUPPORT FOLICT
FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE
EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Farichild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufactures of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed application, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Farichild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handing and storage and provide access to Farichild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address and warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Farichild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

FDZ391P Rev.B1 7 www.fairchildsemi.com